

# 2SK3907

## Switching Regulator Applications

- Small gate charge:  $Q_g = 60 \text{ nC}$  (typ.)
- Low drain-source ON resistance:  $R_{DS(ON)} = 0.18 \Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 12 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS} = 500 \mu\text{A}$  ( $V_{DS} = 500 \text{ V}$ )
- Enhancement model:  $V_{th} = 2.0\sim 4.0 \text{ V}$  ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 1 \text{ mA}$ )

## Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristic		Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	500	V
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		$V_{DGR}$	500	V
Gate-source voltage		$V_{GSS}$	$\pm 30$	V
Drain current	DC (Note 1)	$I_D$	23	A
	Pulse (Note 1)	$I_{DP}$	92	
Drain power dissipation ( $T_c = 25^\circ\text{C}$ )		$P_D$	150	W
Single pulse avalanche energy (Note 2)		$E_{AS}$	552	mJ
Avalanche current		$I_{AR}$	23	A
Repetitive avalanche energy (Note 3)		$E_{AR}$	15	mJ
Channel temperature		$T_{ch}$	150	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	-55~150	$^\circ\text{C}$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case	$R_{th(ch-c)}$	0.833	$^\circ\text{C/W}$
Thermal resistance, channel to ambient	$R_{th(ch-a)}$	50	$^\circ\text{C/W}$

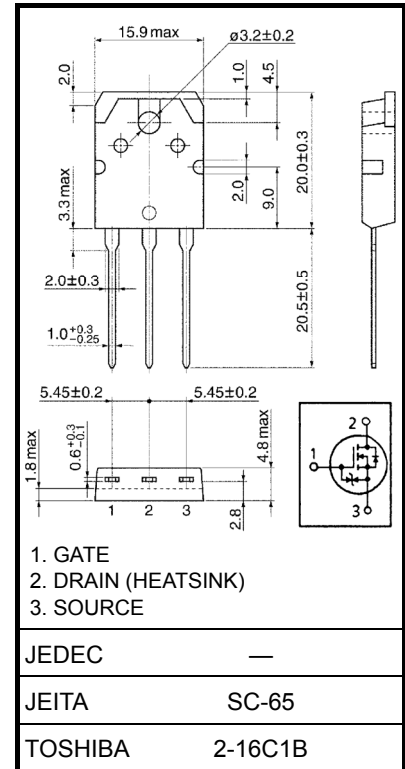
Note 1: Ensure that the channel temperature does not exceed  $150^\circ\text{C}$  during use of the device.

Note 2:  $V_{DD} = 90 \text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$  (initial),  $L = 1.77 \text{ mH}$ ,  $I_{AR} = 23 \text{ A}$ ,  $R_G = 25 \Omega$

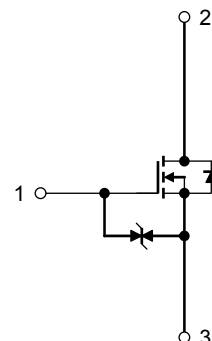
Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm



Weight: 4.6 g (typ.)



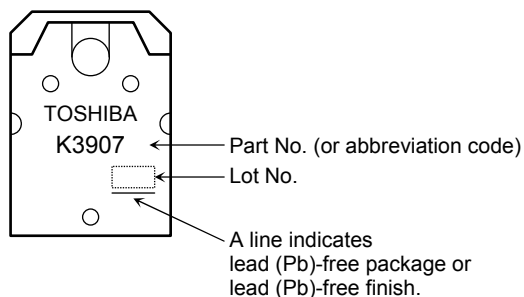
## Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		$I_{GSS}$	$V_{GS} = \pm 25\text{ V}, V_{DS} = 0\text{ V}$	—	—	$\pm 10$	$\mu\text{A}$
Gate-source breakdown voltage		$V_{(BR)GSS}$	$I_D = \pm 10\ \mu\text{A}, V_{DS} = 0\text{ V}$	$\pm 30$	—	—	V
Drain cutoff current		$I_{DSS}$	$V_{DS} = 500\text{ V}, V_{GS} = 0\text{ V}$	—	—	500	$\mu\text{A}$
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	500	—	—	V
Gate threshold voltage		$V_{th}$	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	2.0	—	4.0	V
Drain-source ON resistance		$R_{DS(ON)}$	$V_{GS} = 10\text{ V}, I_D = 11.5\text{ A}$	—	0.18	0.23	$\Omega$
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 11.5\text{ A}$	3.4	12	—	S
Input capacitance		$C_{iss}$	$V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	4250	—	pF
Reverse transfer capacitance		$C_{rss}$		—	10	—	
Output capacitance		$C_{oss}$		—	420	—	
Switching time	Rise time	$t_r$		—	12	—	ns
	Turn-on time	$t_{on}$		—	45	—	
	Fall time	$t_f$		—	10	—	
	Turn-off time	$t_{off}$		Duty $\leq 1\%$ , $t_w = 10\ \mu\text{s}$	—	80	
Total gate charge		$Q_g$	$V_{DD} \approx 400\text{ V}, V_{GS} = 10\text{ V}, I_D = 23\text{ A}$	—	60	—	nC
Gate-source charge		$Q_{gs}$		—	50	—	
Gate-drain charge		$Q_{gd}$		—	10	—	

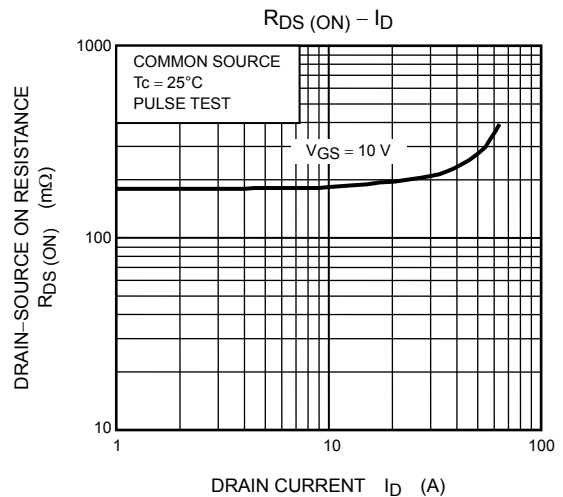
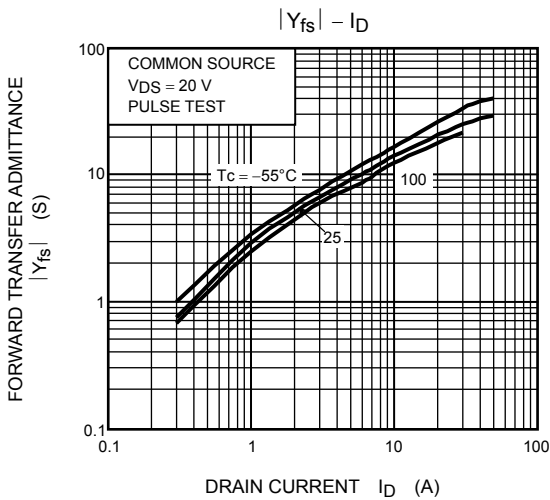
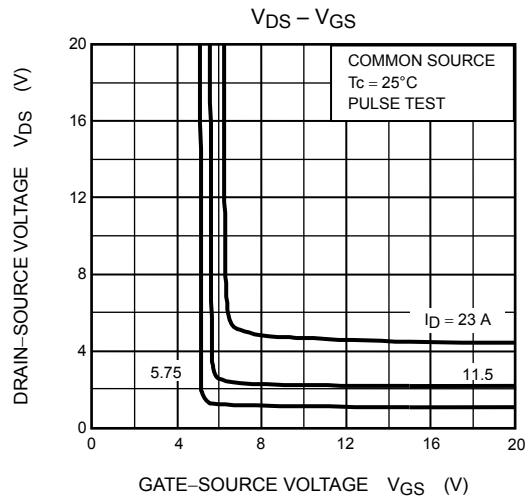
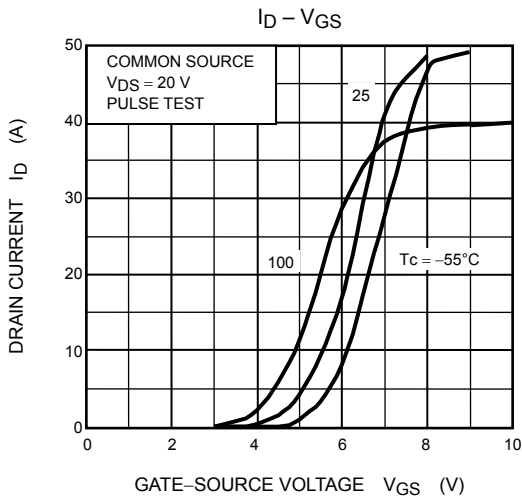
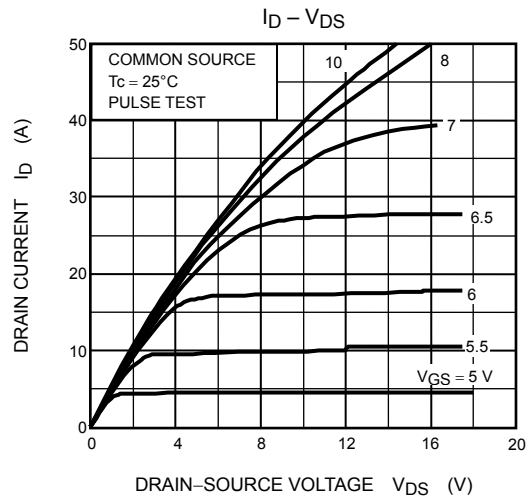
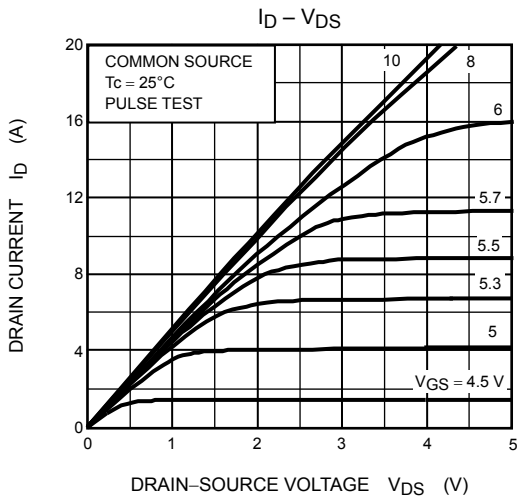
## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)		$I_{DR}$	—	—	—	23	A
Pulse drain reverse current (Note 1)		$I_{DRP}$	—	—	—	92	A
Forward voltage (diode)		$V_{DSF}$	$I_{DR} = 23\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.7	V
Reverse recovery time		$t_{rr}$	$I_{DR} = 23\text{ A}, V_{GS} = 0\text{ V},$	—	1350	—	ns
Reverse recovery charge		$Q_{rr}$	$dI_{DR}/dt = 100\text{ A}/\mu\text{s}$	—	24	—	$\mu\text{C}$

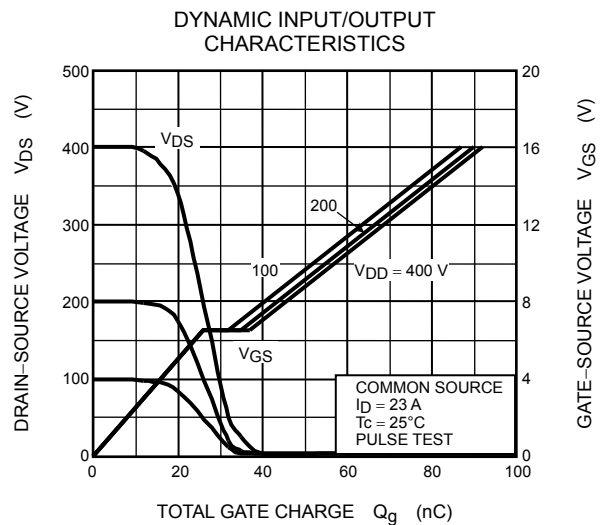
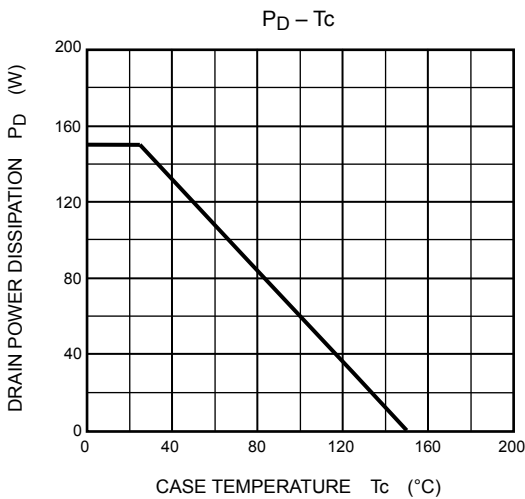
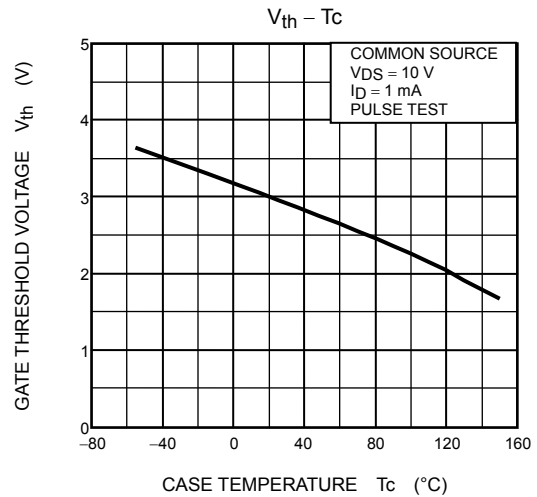
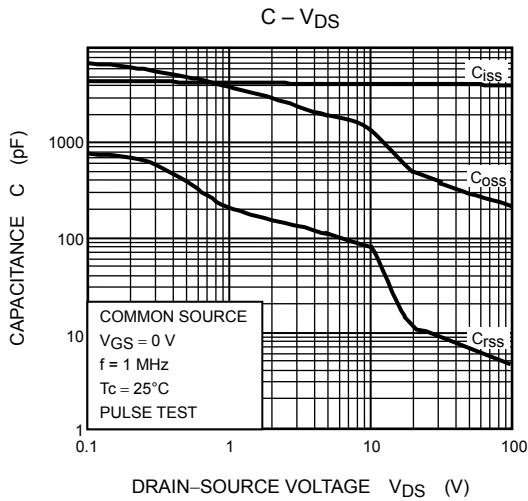
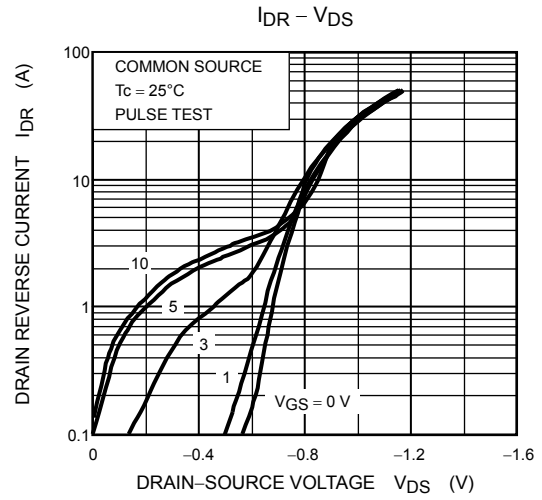
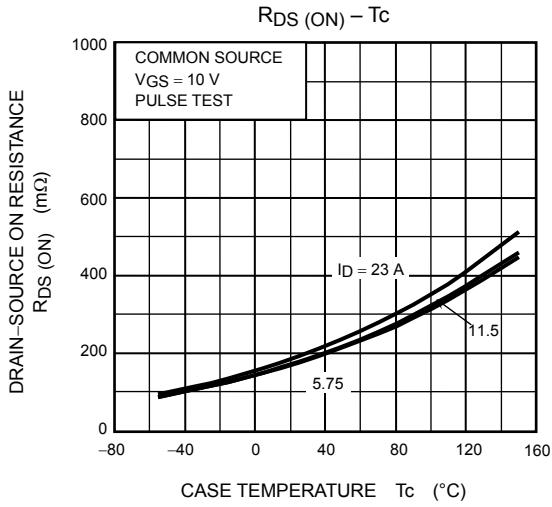
## Marking



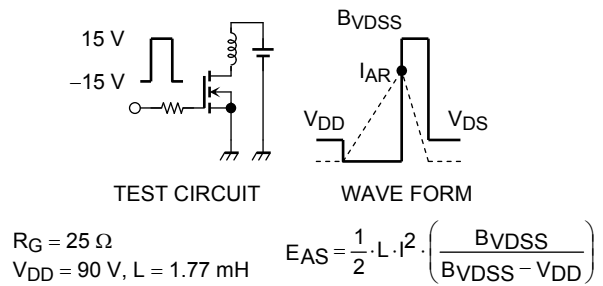
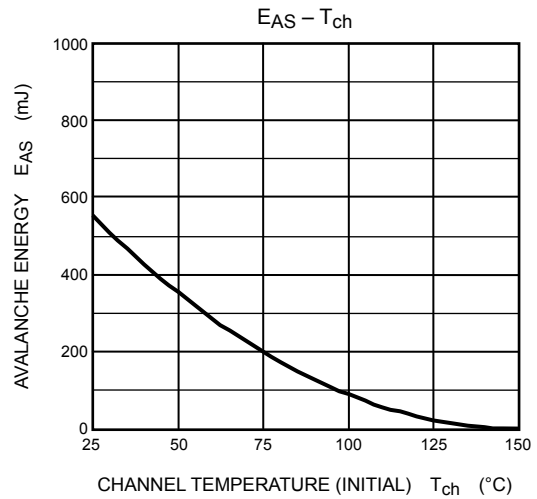
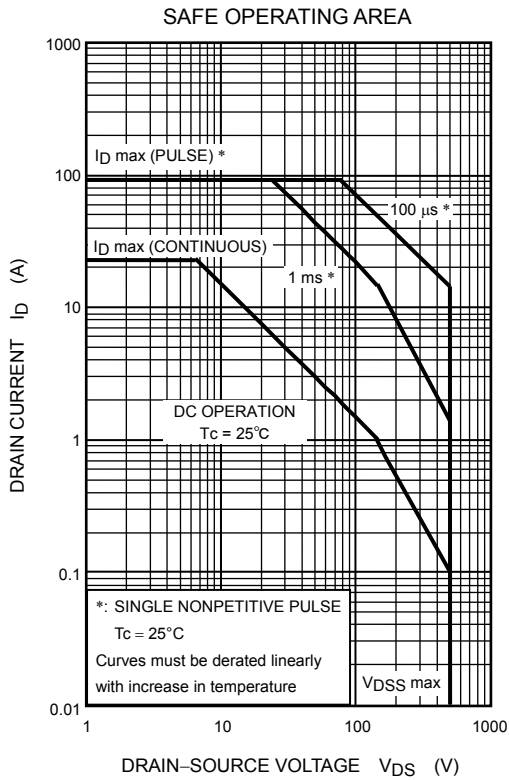
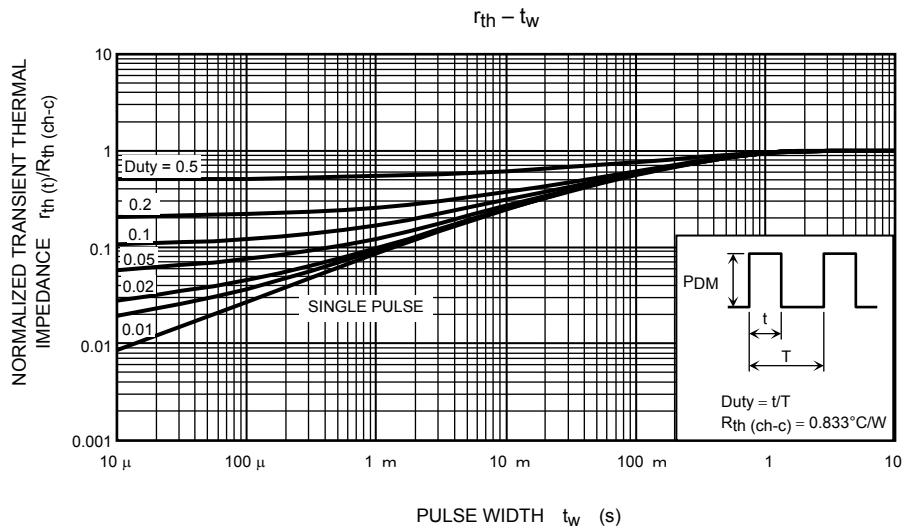
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